1. General description

PNP low V_{CEsat} transistor and NPN Resistor- Equipped Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- Low V_{CEsat} and resistor-equipped transistor in one package
- Low threshold voltage (<1 V) compared to MOSFET
- · Low drive power required
- Space-saving solution
- Reduction of component count
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Supply line switches
- · Battery charger switches
- · High-side switches for LEDs, drivers and backlights
- Portable equipment

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
TR1; PNP lo	w V _{CEsat} transistor						
V_{CEO}	collector-emitter voltage	open base		-	-	-40	V
I _C	collector current			-	-	-500	mA
R _{CEsat}	collector-emitter saturation resistance	I _C = -500 mA; I _B = -50 mA; T _{amb} = 25 °C	[1]	-	440	700	mΩ
TR2; NPN re	esistor-equipped transisto	r					
V _{CEO}	collector-emitter voltage	open base		-	-	50	V
Io	output current			-	-	100	mA
R1	bias resistor 1 (input)		[2]	33	47	61	kΩ
R2/R1	bias resistor ratio		[2]	8.0	1	1.2	

^[1] Pulse test: $t_p \le 300 \mu s$; $\delta \le 0.02$



^[2] See "Section 11: Test information" for resistor calculation and test conditions.

40 V 500 mA PNP/NPN loadswitch double transistor

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1		C1 I2 GND2
2	B1	base TR1	П6 П5 П4	
3	O2	output (collector) TR2		R1 R2
4	GND2	GND (emitter) TR2		TR2
5	12	input (base) TR2	H ₁ H ₂ H ₃	TR1
6	C1	collector TR1	TSSOP6 (SOT363)	E1 B1 O2 sym036

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PBLS4005Y-Q		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	<u>SOT363</u>

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBLS4005Y-Q	S5%

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
TR1; PNP Io	w V _{CEsat} transistor					
V_{CBO}	collector-base voltage	open emitter		-	-40	V
V_{CEO}	collector-emitter voltage	open base		-	-40	V
V _{EBO}	emitter-base voltage	open collector		-	-6	V
Ic	collector current			-	-500	mA
I _{CM}	peak collector current	t _p ≤ 1 ms; single pulse		-	-1	А
I _B	base current			-	-50	mA
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms		-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
TR2; NPN re	esistor-equipped transistor					
V _{CBO}	collector-base voltage	open emitter		-	50	V
V_{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	10	V
V _I	input voltage	positive		-	40	V
		negative		-	-10	V
Io	output current			-	100	mA
I _{CM}	peak collector current	t _p ≤ 1 ms; single pulse		-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Per device						
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C		-	300	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

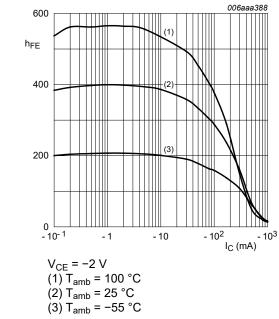
^[1] Device mounted on an FR4 PCB, single-sided, $35~\mu m$ copper, tin-plated and standard footprint.

10. Characteristics

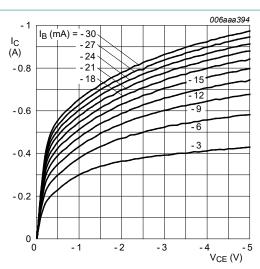
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
TR1; PNP I	ow V _{CEsat} transistor			I			
I _{CBO}	collector-base cut-off	V _{CB} = -40 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
	current	V _{CB} = -40 V; I _E = 0 A; T _i = 150 °C		-	-	-50	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-100	nA
h _{FE}	DC current gain	V_{CE} = -2 V; I_{C} = -10 mA; T_{amb} = 25 °C		200	-	-	
		V _{CE} = -2 V; I _C = -100 mA; T _{amb} = 25 °C	[1]	150	-	-	
		V _{CE} = -2 V; I _C = -500 mA; T _{amb} = 25 °C	[1]	40	-	-	
V _{CEsat}	collector-emitter	I_C = -10 mA; I_B = -0.5 mA; T_{amb} = 25 °C		-	-	-50	mV
	saturation voltage	I_C = -100 mA; I_B = -5 mA; T_{amb} = 25 °C		-	-	-130	mV
		I _C = -200 mA; I _B = -10 mA; T _{amb} = 25 °C		-	-	-200	mV
		I _C = -500 mA; I _B = -50 mA; T _{amb} = 25 °C	[1]	-	-	-350	mV
R _{CEsat}	collector-emitter saturation resistance		[1]	-	440	700	mΩ
V _{BEsat}	base-emitter saturation voltage		[1]	-	-	-1.2	V
V_{BEon}	base-emitter turn-on voltage	V _{CE} = -2 V; I _C = -100 mA; T _{amb} = 25 °C	[1]	-	-	-1.1	V
C _c	collector capacitance	V_{CB} = -10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	10	pF
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -100 mA; f = 100 MHz; T_{amb} = 25 °C		100	300	-	MHz
TR2; NPN r	esistor-equipped transisto	•					
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_{E} = 0 \text{ A}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = 30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	1	μA
	current	V _{CE} = 30 V; I _B = 0 A; T _j = 150 °C		-	-	50	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	90	μA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 5 mA; T _{amb} = 25 °C		80	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	150	mV
V _{I(off)}	off-state input voltage	V _{CE} = 5 V; I _C = 100 μA; T _{amb} = 25 °C		-	1.2	0.8	V
V _{I(on)}	on-state input voltage	V _{CE} = 0.3 V; I _C = 5 mA; T _{amb} = 25 °C		3	1.6	-	V
R1	bias resistor 1 (input)		[2]	33	47	61	kΩ
R2/R1	bias resistor ratio		[2]	0.8	1	1.2	
C _c	collector capacitance	V_{CB} = 10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	2.5	pF

^[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$ [2] See "Section 11: Test information" for resistor calculation and test conditions.

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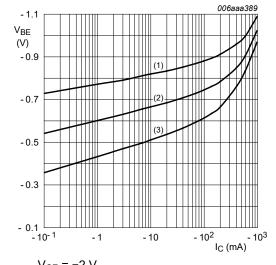


TR1 (PNP): DC current gain as a function of Fig. 1. collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$

Fig. 2. TR1 (PNP): Collector current as a function of collector-emitter voltage; typical values



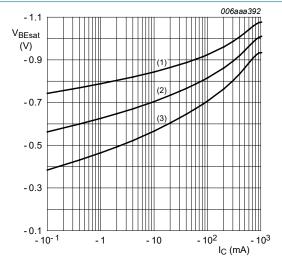
 $V_{CE} = -2 V$

(1) $T_{amb} = -55$ °C

(2) T_{amb} = 25 °C

(3) $T_{amb} = 100 \, ^{\circ}C$

TR1 (PNP): Base-emitter voltage as a function Fig. 3. of collector current; typical values



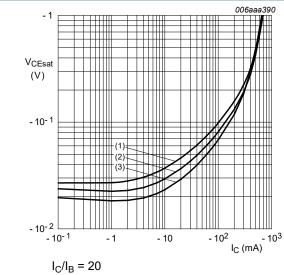
 $I_{\rm C}/I_{\rm B}=20$

(1) $T_{amb} = -55$ °C

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = 100 \, ^{\circ}C$

Fig. 4. TR1 (PNP): Base-emitter saturation voltage as a function of collector current; typical values

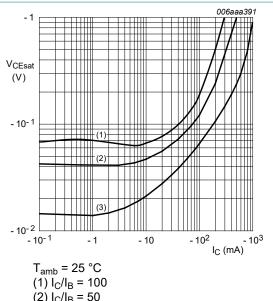


$$I_{\rm C}/I_{\rm B} = 20$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 5. TR1 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values

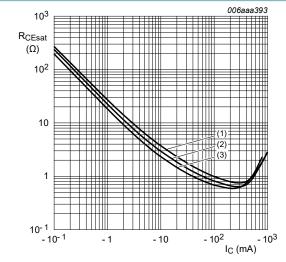


(2)
$$I_C/I_B = 50$$

(2)
$$I_C/I_B = 50$$

(3) $I_C/I_B = 10$

Fig. 6. TR1 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values

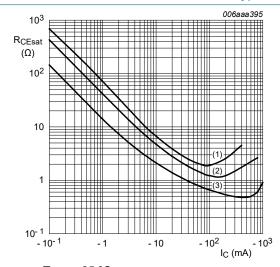


$$I_{\rm C}/I_{\rm B}=20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

$$(3) T_{amb} = -55 °C$$

Fig. 7. TR1 (PNP): Collector-emitter saturation resistance as a function of collector current; typical values



$$T_{amb}$$
 = 25 °C

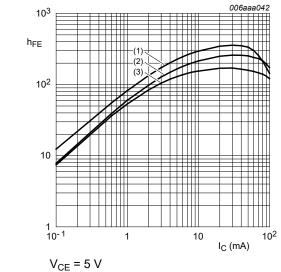
$$(1) I_{\rm C}/I_{\rm B} = 100$$

(2)
$$I_{\rm C}/I_{\rm B} = 50$$

(3)
$$I_C/I_B = 10$$

Fig. 8. TR1 (PNP): Collector-emitter saturation resistance as a function of collector current; typical values

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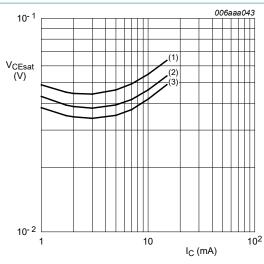
$$V_{CE} = 5 V$$

$$(1) T_{amb} = 150 °C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 9. TR2 (NPN): DC current gain as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

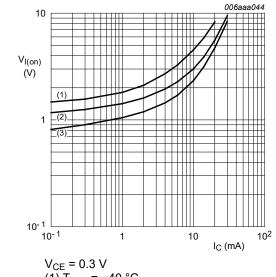
(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2) $T_{amb} = 25 \, ^{\circ}C$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 10. TR2 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values

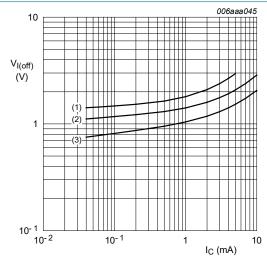


$$(1) T_{amb} = -40 °C$$

$$(2) T_{amb} = 25 °C$$

$$(3) T_{amb} = 100 °C$$

of collector current; typical values



$$V_{CE} = 5 V$$

$$(1) T_{amb} = -40 °C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 11. TR2 (NPN): On-state input voltage as a function | Fig. 12. TR2 (NPN): Off-state input voltage as a function of collector current; typical values

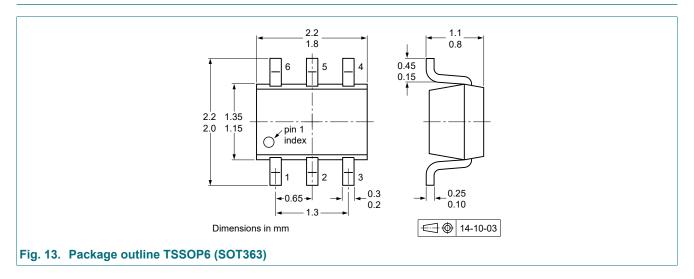
11. Test information

Quality information

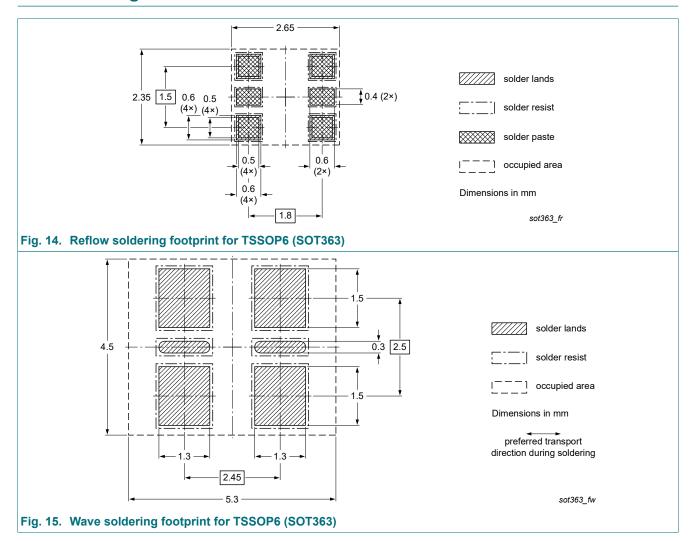
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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12. Package outline



13. Soldering



40 V 500 mA PNP/NPN loadswitch double transistor

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBLS4005Y-Q v.1	20230601	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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PBLS4005Y-Q

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